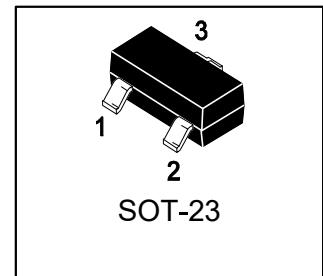


# **S-BAS21L**

## High Voltage Switching Diode

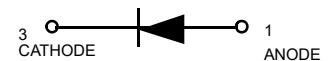
### **1. FEATURES**

- We declare that the material of product compliance with RoHS requirements and Halogen Free.
- S- prefix for automotive and other applications requiring unique site and control change requirements; AEC-Q101 qualified and PPAP capable.



### **2. DEVICE MARKING AND RESISTOR VALUES**

Device	Marking	Shipping
BAS21L	JS	3000/Tape&Reel



### **3. MAXIMUM RATINGS(Ta = 25°C)**

Parameter	Symbol	Limits	Unit
Continuous Reverse Voltage	VR	250	V
Peak Forward Current	IF	225	mA
Peak Forward Surge Current	IFSM	625	mA

### **4. THERMAL CHARACTERISTICS**

Parameter	Symbol	Limits	Unit
Total Device Dissipation FR-5 Board, (Note 1) TA = 25°C Derate above 25°C	PD	225 1.8	mW mW/°C
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) TA = 25°C Derate above 25°C	PD	300 2.4	mW mW/°C
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	417	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55~+150	°C

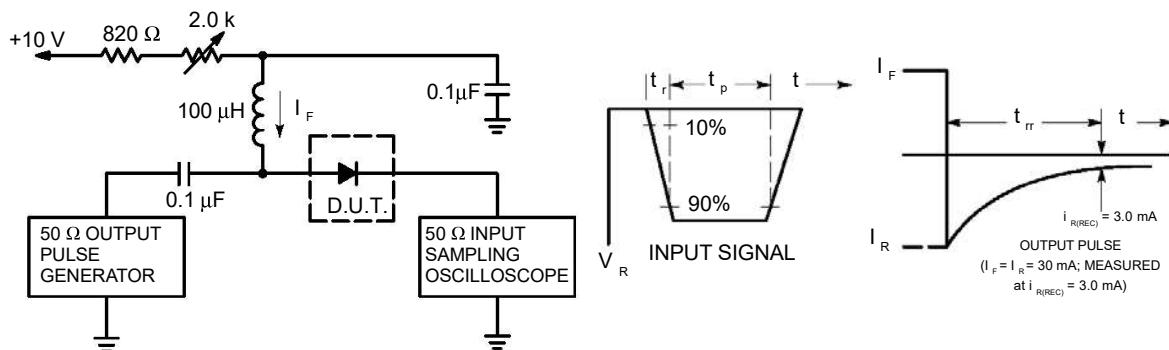
1. FR-5 = 1.0 x 0.75 x 0.062 in.

2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.



5. ELECTRICAL CHARACTERISTICS ( $T_a = 25^\circ C$ )

CHARACTERISTICS	Symbol	Min	Max	Unit
Reverse Voltage Leakage Current ( $VR=200V$ ) ( $VR=200V, TJ = 150^\circ C$ )	$I_R$	-	0.1 100	$\mu A$
Reverse Breakdown Voltage ( $I_{BR} = 100 \mu A$ )	$V_{BR}$	250	-	V
Forward voltage ( $I_F = 100mA$ ) ( $I_F = 200mA$ )	$V_F$	- -	1000 1250	mV
Diode capacitance ( $f=1MHz, VR = 0$ )	$C_d$	-	5	pF
Reverse Recovery Time ( $I_F = I_R = 30mA, RL = 100\Omega$ )	$T_{rr}$	-	50	nS



Notes: 1. A 2.0 kΩ variable resistor adjusted for a Forward Current ( $I_F$ ) of 30 mA.

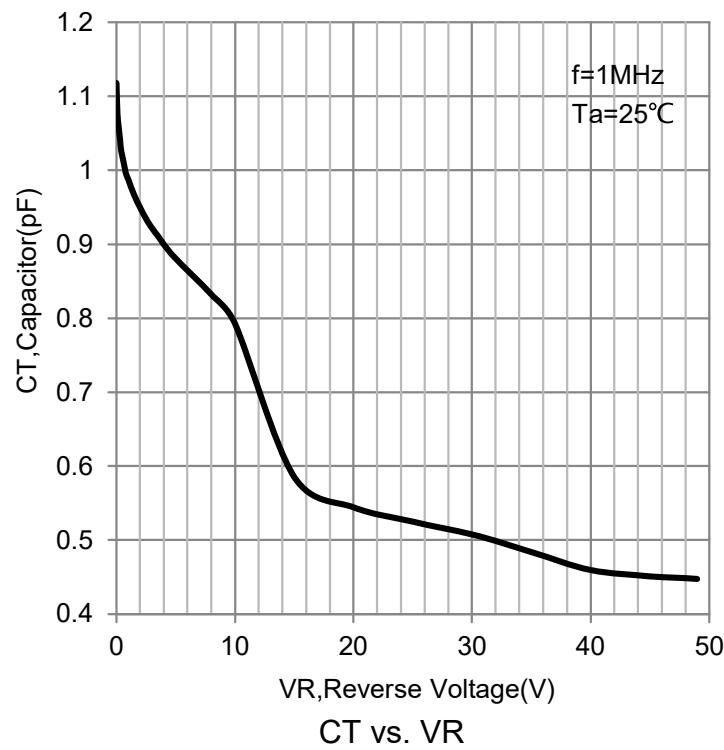
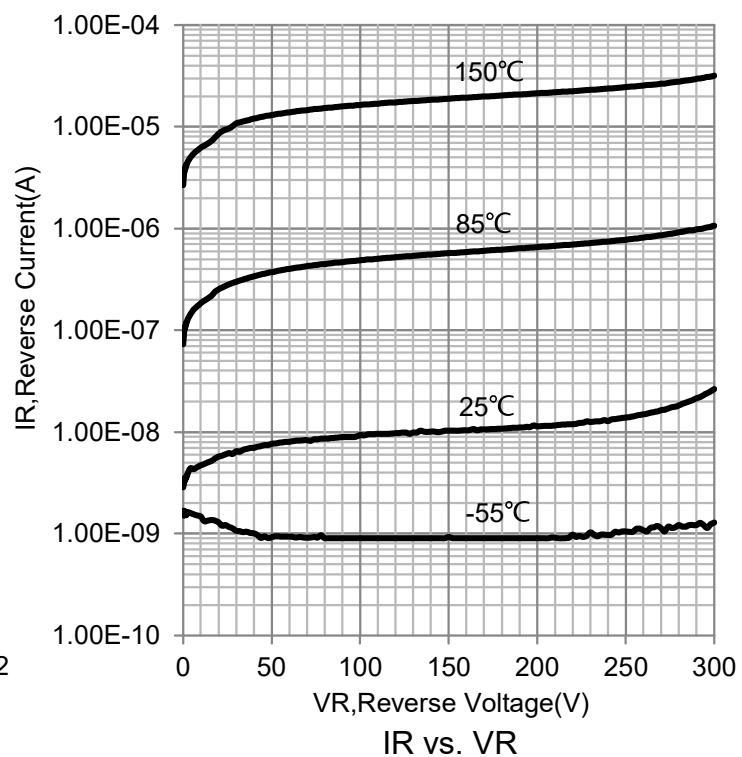
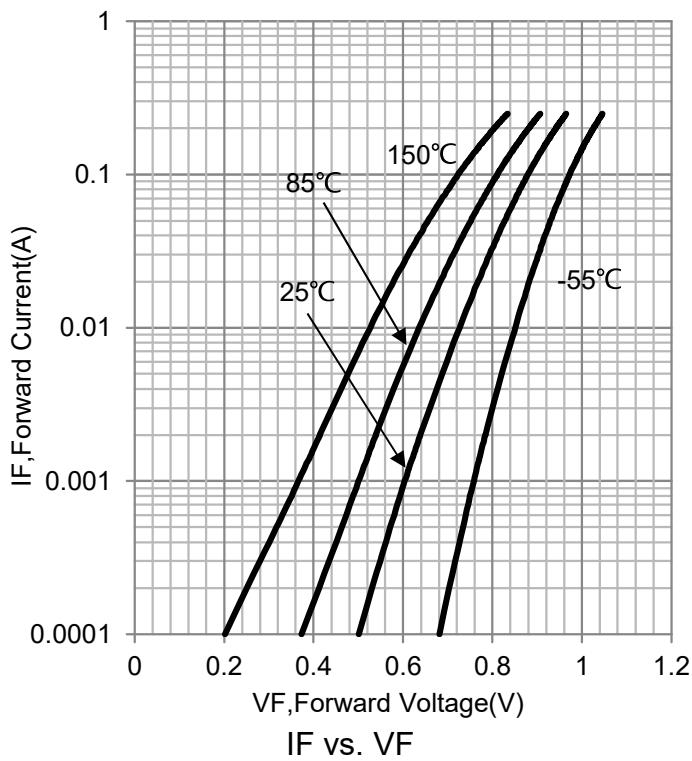
2. Input pulse is adjusted so  $I_{R(peak)}$  is equal to 30 mA.

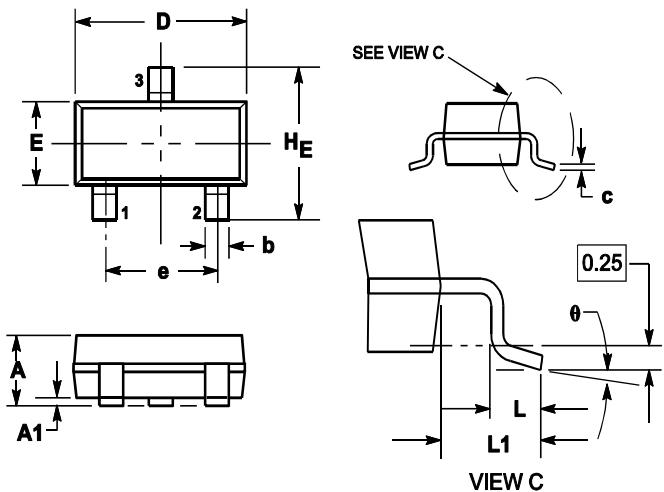
3.  $t_p \gg t_{rr}$

Figure 1. Recovery Time Equivalent Test Circuit



## 6.ELECTRICAL CHARACTERISTICS CURVES



**7. OUTLINE AND DIMENSIONS**

Notes:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.89	1	1.11	0.035	0.04	0.044
A1	0.01	0.06	0.1	0.001	0.002	0.004
b	0.37	0.44	0.5	0.015	0.018	0.02
c	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.9	3.04	0.11	0.114	0.12
E	1.20	1.3	1.4	0.047	0.051	0.055
e	1.78	1.9	2.04	0.07	0.075	0.081
L	0.10	0.2	0.3	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
H_E	2.10	2.4	2.64	0.083	0.094	0.104
θ	0°	---	10°	0°	---	10°

**8. SOLDERING FOOTPRINT**